2SK1483C

N-CHANNEL MOSFET FOR SWITCHING

R07DS1263EJ0200
Rev.2.00
Jun 19, 2015

Description

The 2SK1483C, N-channel vertical type MOSFET designed for general-purpose switch, is a device which can be driven directly by a 2.5 V power source.

Features

- Directly driven by a 2.5 V power source.
- Low on-state resistance
  - $R_{DS(on)1}$ = 63 m Ω MAX. (V_{GS} = 4.5 V, I_D = 2.0 A)
  - $R_{DS(on)2}$ = 65 mΩ MAX. (V_{GS} = 4.0 V, I_D = 2.0 A)
  - $R_{DS(on)3}$ = 91 mΩ MAX. (V_{GS} = 2.5 V, I_D = 2.0 A)

Ordering Information

Part Number	Lead Plating	Packing	Package
2SK1483C-T1-AZ/AY	-AZ : Sn-Bi , -AY : Pure Sn	1000p/Reel	SC-62 (3p PoMM)

Remark "-AZ/AY" indicates Pb-free. This product does not contain Pb in external electrode and other parts.

Marking XC

Absolute Maximum Ratings (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	30	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±12	V
Drain Current (DC)	$I_{D(DC)}$	±3.5	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	±14	A
Total Power Dissipation Note2	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	−55 to +150	°C

Note1 PW ≤ 10 μs, Duty Cycle ≤ 1%

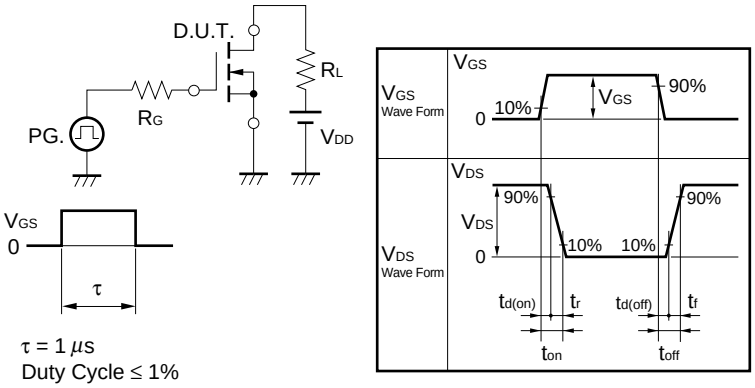
Note2 16 cm^2 X 0.7mm, ceramic substrate used

Electrical Characteristics (T_A = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V			10	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ±12 V, V_{DS} = 0 V			±10	μA
Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10V, I_D = 1 mA	0.5	1.0	1.5	V
Forward Transfer Admittance **Note**	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 2.0 A	1.0	4.9		S
Drain to Source On-state Resistance **Note**	$R_{DS(on)1}$	V_{GS} = 4.5 V, I_D = 2.0 A		50	63	mΩ
	$R_{DS(on)2}$	V_{GS} = 4.0 V, I_D = 2.0 A		52	65	mΩ
	$R_{DS(on)3}$	V_{GS} = 2.5 V, I_D = 2.0 A		68	91	mΩ
Input Capacitance	C_{iss}	V_{DS} = 10 V,		260		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V,		60		pF
Reverse Transfer Capacitance	C_{rss}	f = 1.0 MHz		35		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 10 V,		28		ns
Rise Time	t_r	I_D = 2 A,		65		ns
Turn-off Delay Time	$t_{d(off)}$	V_{GS} = 4 V,		98		ns
Fall Time	t_f	R_G = 10 Ω		80		ns
Total Gate Charge	Q_G	I_D = 3.5 A, V_{DD} = 24 V, V_{GS} = 4 V		4		nC
Body Diode Forward Voltage **Note**	$V_{F(S-D)}$	I_F = 3.5 A, V_{GS} = 0 V		0.89		V

Note Pulsed

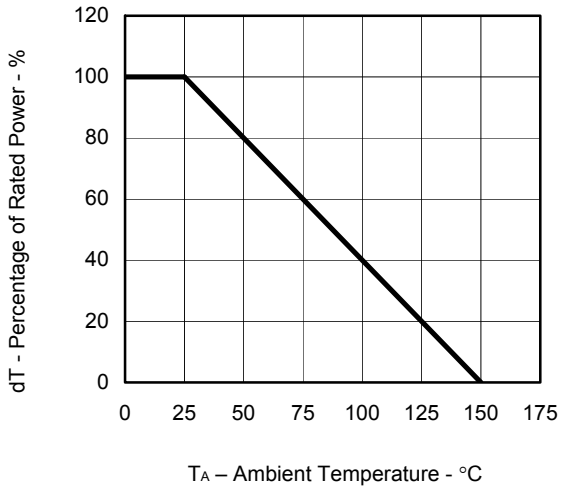
Test Circuit Switching Time



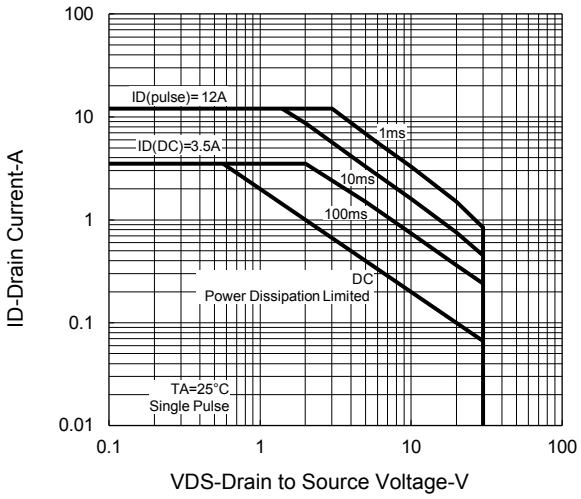
τ = 1 μs
Duty Cycle ≤ 1%

Typical Characteristics (T_A = 25°C)

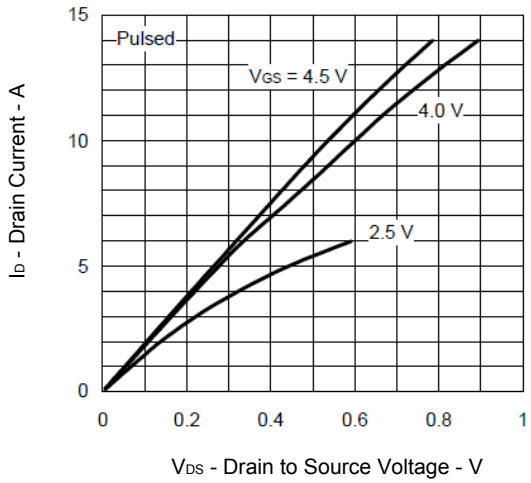
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



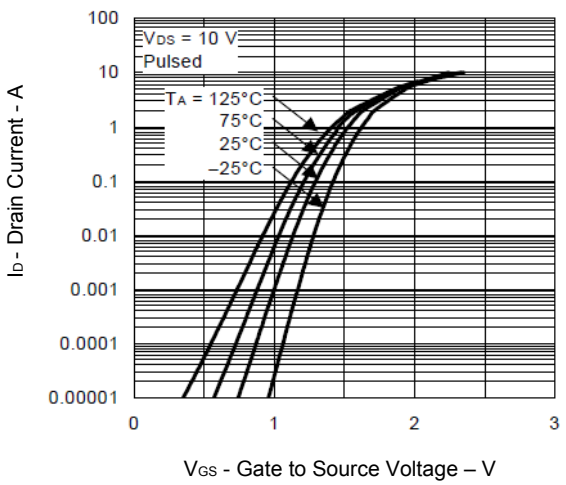
FORWARD BIAS SAFE OPERATING AREA



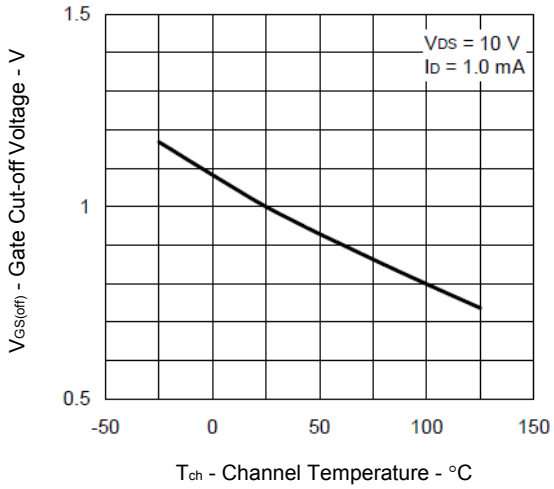
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



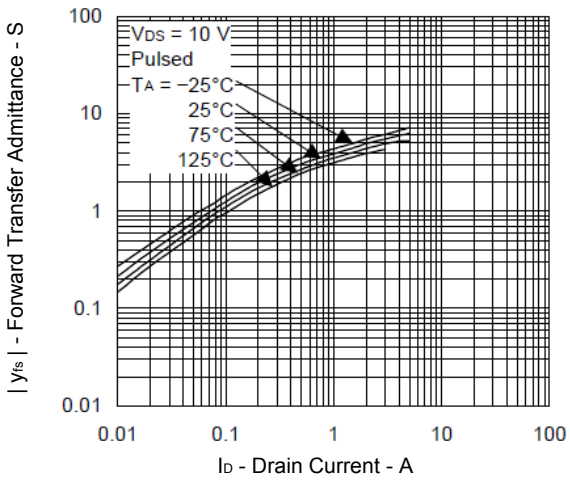
FORWARD TRANSFER CHARACTERISTICS



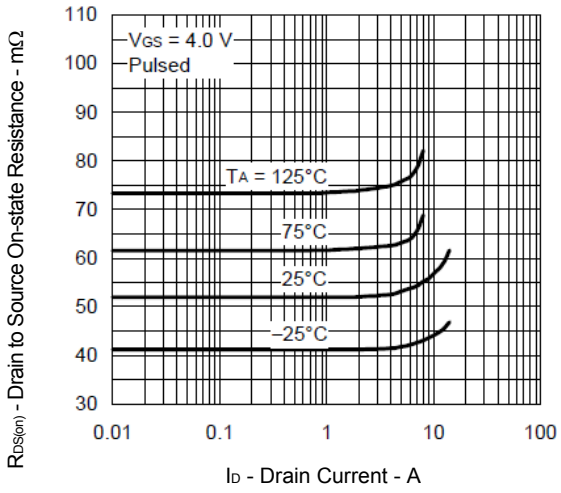
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



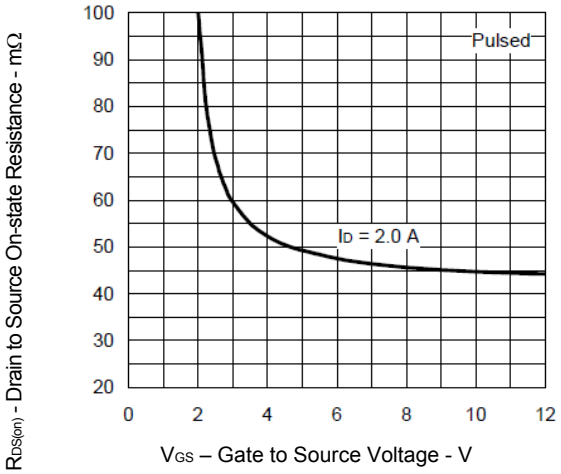
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



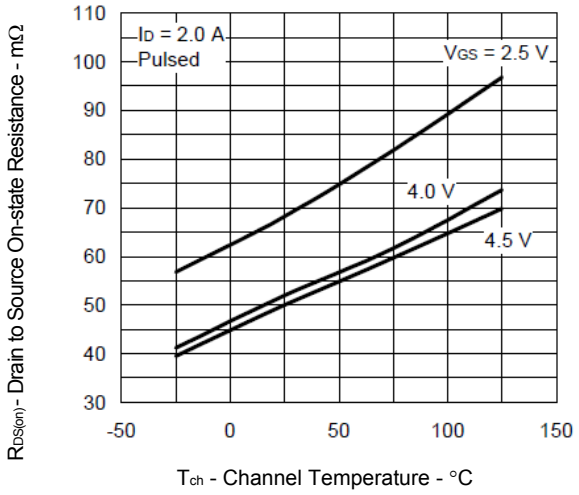
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



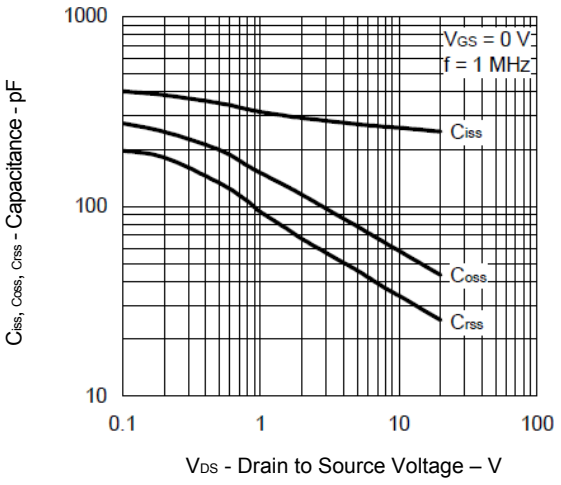
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



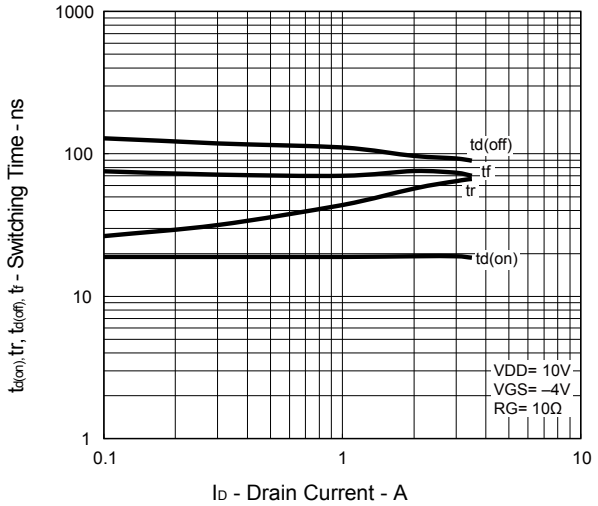
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
CHANNEL TEMPERATURE



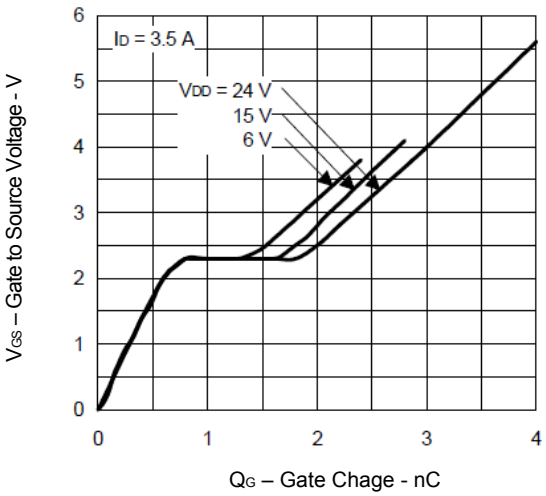
CAPACITANCE vs.
DRAIN TO SOURCE VOLTAGE



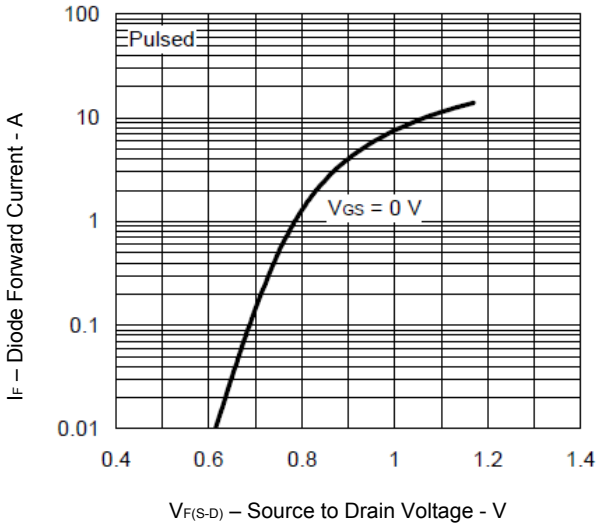
SWITCHING CHARACTERISTICS



DYNAMIC INPUT CHARACTERISTICS

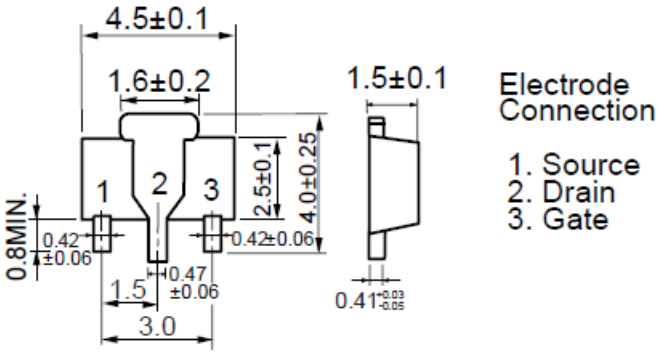


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

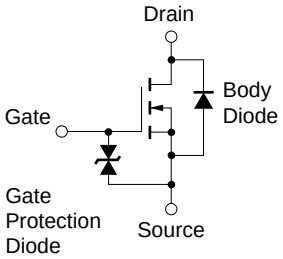


Package Drawings (Unit: mm)

SC-62 (3pPoMM)



Equivalent Circuit



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Rev.	Date	Description	
		Page	Summary
1.00	Sep , 2013	–	First Edition Issued
2.00	Jun , 2015	3	Added FORWARD BIAS SAFE OPERATING AREA
		4	Changed SWITCHING CHARACTERISTICS

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Renesas Electronics America Inc.
2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3
Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HALII Stage, Indiranagar, Bangalore, India
Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.
12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141

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